

INCHANGE SEMICONDUCTOR

isc Silicon NPN Darlington Power Transistor

2SD2014

DESCRIPTION

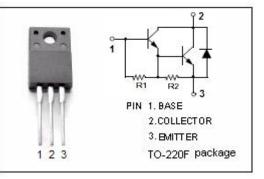
- Collector-Emitter Breakdown Voltage-
- : V_{(BR)CEO}= 80V(Min)
- Collector-Emitter Saturation Voltage-: V_{CE(sat)}= 1.5V(Max) @I_C= 3A
- High DC Current Gain
- : h_{FE}= 2000(Min) @ I_C= 3A, V_{CE}= 2V
- Complement to Type 2SB1257
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

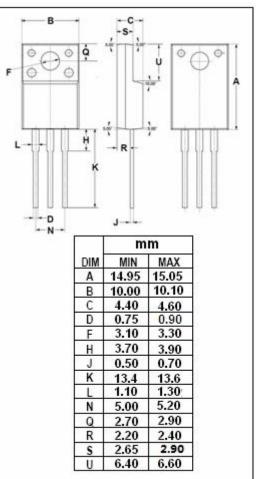
APPLICATIONS

• Designed of driver of solenoid, relay and motor, series regulator and general purpose applications

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	120	V
V _{CEO}	Collector-Emitter Voltage 80		V
V _{EBO}	Emitter-Base Voltage	6	V
lc	Collector Current-Continuous	4	A
I _B	Base Current-Continuous	0.5	A
Pc	Collector Power Dissipation @ T _C =25°C	25	W
TJ	Junction Temperature	150	°C
T _{stg}	Storage Temperature Range	-55~150	°C





isc website: www.iscsemi.com



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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA ; I _B = 0	80			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 3A; I _B = 3mA			1.5	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 3A; I _B = 3mA			2.0	V
Ісво	Collector Cutoff Current	V _{CB} = 120V; I _E = 0			10	μA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 6V; I _C = 0			10	mA
h _{FE}	DC Current Gain	I _C = 3A ; V _{CE} = 2V	2000			
fT	Current-Gain—Bandwidth Product	I _E = -0.1A ; V _{CE} = 12V		75		MHz
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V,f _{test} = 1MHz		45		pF

Switching times

t _{on}	Turn-on Time		1.0	μ S
t _{stg}	Storage Time	I _C = 3A; I _{B1} = I _{B2} = 10mA; R _L = 10 Ω; V _{CC} = 30V	4.0	μ S
t _f	Fall Time		1.5	μ S

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